

EAST Search History (53 pp.)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	15250	((257/79) or (257/8\$1) or (257/9\$1) or (257/100) or (257/101) or (257/102) or (257/103) or (257/190) or (372/43.01) or (372/44.01)).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/01/05 10:37
L3	3	2 and (boron adj phosphide BP) near6 buffer and (GaNP GaPN gallium adj nitride adj phosphide gallium adj phosphide adj nitride) and GaInN	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 10:40
L4	3	(showa adj denko.as. "udagawa.in") and (boron adj phosphide BP) near6 buffer and (GaNP GaPN gallium adj nitride adj phosphide gallium adj phosphide adj nitride) and GaInN	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 10:41
S1	0	("(GaNPorgalliumadjnitrideadjphosphide)andlight-emitting.ti,ab.").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 07:56
S2	12	(GaNP or gallium adj nitride adj phosphide) and light-emitting.ti,ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 07:10
S3	4	(GaNP or "GaN.sub.1-x.P.sub.x" or gallium adj nitride adj phosphide) and light-emitting.ti,ab. and boron adj phosphide near3 buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 16:53
S4	4	(GaNP or "GaN.sub.1-x.P.sub.x" or gallium adj nitride adj phosphide) and light-emitting.ti,ab. and (BP or boron adj phosphide) near6 buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 16:54
S5	7	(GaNP or "GaN.sub.1-x.P.sub.x" or gallium adj nitride adj phosphide or GaN near6 P or GaN near6 phosphorus or gallium adj nitride near6 (phosphorus or P)) and light-emitting.ti,ab. and (BP or boron adj phosphide) near6 buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 16:58

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S6	4	(GaNP or "GaN.sub.1-x.P.sub.x" or gallium adj nitride adj phosphide or GaN near6 P or GaN near6 phosphorus or gallium adj nitride near6 (phosphorus or P)) and (257/8\$5.ccls. or 257/9\$5.ccls. or 257/100.ccls. or 257/101.ccls. or 257/102.ccls. or 257/103.ccls.) and (BP or boron adj phosphide) near6 buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 17:07
S7	4	(GaNP or GaPN or gallium adj phosphide adj nitride or "GaN.sub.x.P.sub.1-x" or "GaN.sub.1-x.P.sub.x" or gallium adj nitride adj phosphide or GaN near6 P or GaN near6 phosphorus or gallium adj nitride near6 (phosphorus or P)) and (257/8\$5.ccls. or 257/9\$5.ccls. or 257/100.ccls. or 257/101.ccls. or 257/102.ccls. or 257/103.ccls.) and (BP or boron adj phosphide) near6 buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 17:09
S8	4	(GaNP or GaPN or gallium adj phosphide adj nitride or "GaN.sub.x.P.sub.1-x" or "GaN.sub.1-x.P.sub.x" or gallium adj nitride adj phosphide or GaN near6 P or GaN near6 phosphorus or gallium adj nitride near6 (phosphorus or P) or GaN near6 (P or phosphorus)) and (257/8\$5.ccls. or 257/9\$5.ccls. or 257/100.ccls. or 257/101.ccls. or 257/102.ccls. or 257/103.ccls.) and (BP or boron adj phosphide) near6 buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 17:10
S9	4	(GaNP or GaPN or gallium adj phosphide adj nitride or "GaN.sub.x.P.sub.1-x" or "GaN.sub.1-x.P.sub.x" or gallium adj nitride adj phosphide or GaN near6 P or GaN near6 phosphorus or gallium adj nitride near6 (phosphorus or P) or (gallium adj nitride or GaN) near6 (P or phosphorus)) and (257/8\$5.ccls. or 257/9\$5.ccls. or 257/100.ccls. or 257/101.ccls. or 257/102.ccls. or 257/103.ccls.) and (BP or boron adj phosphide) near6 buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 17:28

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S10	342	(GaNP or GaPN or gallium adj phosphide adj nitride or "GaN.sub.x.P.sub.1-x" or "GaN.sub.1-x.P.sub.x" or gallium adj nitride adj phosphide or GaN near6 P or GaN near6 phosphorus or gallium adj nitride near6 (phosphorus or P) or (gallium adj nitride or GaN) near6 (P or phosphorus)) and (257/8\$5.ccls. or 257/9\$5.ccls. or 257/100.ccls. or 257/101.ccls. or 257/102.ccls. or 257/103.ccls.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 17:29
S11	275	(GaNP or GaPN or gallium adj phosphide adj nitride or "GaN.sub.x.P.sub.1-x" or "GaN.sub.1-x.P.sub.x" or gallium adj nitride adj phosphide or GaN near6 P or GaN near6 phosphorus or gallium adj nitride near6 (phosphorus or P) or (gallium adj nitride or GaN) near6 (P or phosphorus)) and (257/8\$5.ccls. or 257/9\$5.ccls. or 257/100.ccls. or 257/101.ccls. or 257/102.ccls. or 257/103.ccls.) and buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 17:30
S12	4	(GaNP or GaPN or gallium adj phosphide adj nitride or "GaN.sub.x.P.sub.1-x" or "GaN.sub.1-x.P.sub.x" or gallium adj nitride adj phosphide or GaN near6 P or GaN near6 phosphorus or gallium adj nitride near6 (phosphorus or P) or (gallium adj nitride or GaN) near6 (P or phosphorus)) and (257/8\$5.ccls. or 257/9\$5.ccls. or 257/100.ccls. or 257/101.ccls. or 257/102.ccls. or 257/103.ccls.) and buffer near12 (boron adj phosphide or bp)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 17:34
S13	489	(257/79).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:35
S14	435	(257/80).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:35

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S15	366	(257/81).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:35
S16	814	(257/82).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:35
S17	106	(257/83).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:35
S18	380	(257/84).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:35
S19	205	(257/85).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:35
S20	229	(257/86).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:35
S21	56	(257/87).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:35
S22	488	(257/88).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:35

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S23	175	(257/89).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:35
S24	83	(257/90).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:36
S25	147	(257/91).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:36
S26	49	(257/92).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:36
S27	146	(257/93).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:36
S28	685	(257/94).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:36
S29	239	(257/95).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:36
S30	445	(257/96).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:36

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S31	327	(257/97).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:36
S32	1241	(257/98).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:36
S33	1351	(257/99).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:36
S34	318	(257/100).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:36
S35	278	(257/101).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:36
S36	308	(257/102).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:36
S37	967	(257/103).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:37
S38	0	("L13orL14orL15orL16orL17orL18orL19orL20orL21orL22orL23orL24orL25orL26orL27orL28orL29orL30orL31orL32orL33orL34orL35orL36orL37").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/30 17:38

EAST Search History

S39	6890	((257/79).CCLS.) or ((257/80).CCLS.) or ((257/81).CCLS.) or ((257/82).CCLS.) or ((257/83).CCLS.) or ((257/84).CCLS.) or ((257/85).CCLS.) or ((257/86).CCLS.) or ((257/87).CCLS.) or ((257/88).CCLS.) or ((257/89).CCLS.) or ((257/90).CCLS.) or ((257/91).CCLS.) or ((257/92).CCLS.) or ((257/93).CCLS.) or ((257/94).CCLS.) or ((257/95).CCLS.) or ((257/96).CCLS.) or ((257/97).CCLS.) or ((257/98).CCLS.) or ((257/99).CCLS.) or ((257/100).CCLS.) or ((257/101).CCLS.) or ((257/102).CCLS.) or ((257/103).CCLS.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 17:40
S40	0	((257/79).CCLS.) or ((257/80).CCLS.) or ((257/81).CCLS.) or ((257/82).CCLS.) or ((257/83).CCLS.) or ((257/84).CCLS.) or ((257/85).CCLS.) or ((257/86).CCLS.) or ((257/87).CCLS.) or ((257/88).CCLS.) or ((257/89).CCLS.) or ((257/90).CCLS.) or ((257/91).CCLS.) or ((257/92).CCLS.) or ((257/93).CCLS.) or ((257/94).CCLS.) or ((257/95).CCLS.) or ((257/96).CCLS.) or ((257/97).CCLS.) or ((257/98).CCLS.) or ((257/99).CCLS.) or ((257/100).CCLS.) or ((257/101).CCLS.) or ((257/102).CCLS.) or ((257/103).CCLS.)) and ganp.ti,ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 17:41
S41	13	((257/79).CCLS.) or ((257/80).CCLS.) or ((257/81).CCLS.) or ((257/82).CCLS.) or ((257/83).CCLS.) or ((257/84).CCLS.) or ((257/85).CCLS.) or ((257/86).CCLS.) or ((257/87).CCLS.) or ((257/88).CCLS.) or ((257/89).CCLS.) or ((257/90).CCLS.) or ((257/91).CCLS.) or ((257/92).CCLS.) or ((257/93).CCLS.) or ((257/94).CCLS.) or ((257/95).CCLS.) or ((257/96).CCLS.) or ((257/97).CCLS.) or ((257/98).CCLS.) or ((257/99).CCLS.) or ((257/100).CCLS.) or ((257/101).CCLS.) or ((257/102).CCLS.) or ((257/103).CCLS.)) and (ganp or (gan or gallium adj nitride) near12 phosphorus)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 17:43

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S42	2	(((257/79).CCLS.) or ((257/80).CCLS.) or ((257/81).CCLS.) or ((257/82).CCLS.) or ((257/83).CCLS.) or ((257/84).CCLS.) or ((257/85).CCLS.) or ((257/86).CCLS.) or ((257/87).CCLS.) or ((257/88).CCLS.) or ((257/89).CCLS.) or ((257/90).CCLS.) or ((257/91).CCLS.) or ((257/92).CCLS.) or ((257/93).CCLS.) or ((257/94).CCLS.) or ((257/95).CCLS.) or ((257/96).CCLS.) or ((257/97).CCLS.) or ((257/98).CCLS.) or ((257/99).CCLS.) or ((257/100).CCLS.) or ((257/101).CCLS.) or ((257/102).CCLS.) or ((257/103).CCLS.)) and buffer near12 (bp or boron adj phosphide) and (ganp or (gan or gallium adj nitride) near12 phosphorus)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 17:44
S43	13	(((257/79).CCLS.) or ((257/80).CCLS.) or ((257/81).CCLS.) or ((257/82).CCLS.) or ((257/83).CCLS.) or ((257/84).CCLS.) or ((257/85).CCLS.) or ((257/86).CCLS.) or ((257/87).CCLS.) or ((257/88).CCLS.) or ((257/89).CCLS.) or ((257/90).CCLS.) or ((257/91).CCLS.) or ((257/92).CCLS.) or ((257/93).CCLS.) or ((257/94).CCLS.) or ((257/95).CCLS.) or ((257/96).CCLS.) or ((257/97).CCLS.) or ((257/98).CCLS.) or ((257/99).CCLS.) or ((257/100).CCLS.) or ((257/101).CCLS.) or ((257/102).CCLS.) or ((257/103).CCLS.)) and (ganp or (gan or gallium adj nitride) near12 phosphorus)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 17:47
S44	4	(((257/79).CCLS.) or ((257/80).CCLS.) or ((257/81).CCLS.) or ((257/82).CCLS.) or ((257/83).CCLS.) or ((257/84).CCLS.) or ((257/85).CCLS.) or ((257/86).CCLS.) or ((257/87).CCLS.) or ((257/88).CCLS.) or ((257/89).CCLS.) or ((257/90).CCLS.) or ((257/91).CCLS.) or ((257/92).CCLS.) or ((257/93).CCLS.) or ((257/94).CCLS.) or ((257/95).CCLS.) or ((257/96).CCLS.) or ((257/97).CCLS.) or ((257/98).CCLS.) or ((257/99).CCLS.) or ((257/100).CCLS.) or ((257/101).CCLS.) or ((257/102).CCLS.) or ((257/103).CCLS.)) and (gan or gallium adj nitride) and ((bp or boron adj phosphide) near12 buffer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 17:53

EAST Search History

S45	0	jp-410242514\$-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 17:54
S46	2	jp-10242514\$-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 17:56
S47	2	jp-10242567\$-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 17:59
S48	2	jp-10242569\$-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 18:09
S49	2	"6316793".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 18:10
S50	2	"6064082".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 18:11
S51	2	"5929467".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 18:11
S52	2	jp-10066769\$-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/30 20:04
S53	0	jp-410066769\$-\$.did.	JPO	OR	ON	2002/05/30 20:05
S54	1	jp-10066769\$-\$.did.	JPO	OR	ON	2002/05/30 20:06
S55	1	jp-11036830\$-\$.did.	JPO	OR	ON	2002/05/30 20:06
S56	0	jp-411036830\$-\$.did.	JPO	OR	ON	2002/05/30 20:06
S57	0	terashima.in. and buffer	JPO	OR	ON	2002/05/30 20:13
S58	1	light-emitting.ti,ab. and ((bp or boron adj phosphide) near10 buffer) and gallium adj nitride.ti,ab.	JPO	OR	ON	2002/05/30 20:14

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S59	1	light-emitting.ti,ab. and ((bp or boron adj phosphide) near10 buffer) and gallium adj nitride	JPO	OR	ON	2002/05/30 20:14
S60	3	(led or light-emitting or light adj emitting).ti,ab. and ((bp or boron adj phosphide) near10 buffer) and gallium adj nitride	JPO	OR	ON	2002/05/30 20:15
S61	4	(GaNP or gallium adj nitride adj phosphide or AlGaNP or aluminum adj gallium adj nitride adj phosphide or "GaN.sub.1ix.P.subx") and light-emitting.ti,ab. and buffer near10 (bp or boron adj phosphide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 07:13
S62	4	(GaNP or gallium adj nitride adj phosphide or AlGaNP or aluminum adj gallium adj nitride adj phosphide or "GaN.sub.1-x.P.sub.x") and light-emitting.ti,ab. and (bp or boron adj phosphide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 07:15
S63	8	((GaN or gallium adj nitride or AlGaN or aluminum adj gallium adj nitride) near6 (P or phosphide)) and light-emitting.ti,ab. and (bp or boron adj phosphide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 07:19
S64	7	((GaN or gallium adj nitride or AlGaN or aluminum adj gallium adj nitride) near6 (P or phosphide)) and light-emitting.ti,ab. and ((bp or boron adj phosphide) near10 buffer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 07:58
S65	4	((GaN or gallium adj nitride or AlGaN or aluminum adj gallium adj nitride) near6 (P or phosphide)) and light-emitting.ti,ab. and ((bp or boron adj phosphide) near10 buffer) and ((mono-crystal or single adj crystal) near6 substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 08:01
S66	8	light-emitting.ti,ab. and ((bp or boron adj phosphide) near10 buffer) and ((mono-crystal or single adj crystal) near6 substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 08:01
S67	325	light-emitting.ti,ab. and ((mono-crystal or single adj crystal) near6 substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 08:15

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S68	184	light-emitting.ti,ab. and ((mono-crystal or single adj crystal) adj substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 08:16
S69	14	light-emitting.ti,ab. and ((mono-crystal or single adj crystal) adj substrate) and GaN.ti,ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 08:17
S70	351	buffer adj layer near3 amorphous	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 08:43
S71	4	(bp or boron adj phosphorus) near6 buffer adj layer near3 amorphous	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 08:44
S72	38	amorphous adj buffer adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 10:42
S73	3	amorphous adj buffer adj layer and (single adj crystal or single-crystal) adj buffer adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 11:23
S74	64	single adj (heterojunction or hetero-junction) and (double adj heterojunction or hetero-junction) and "257"/\$6.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 11:26
S75	58	(single adj (heterojunction or hetero-junction)) and (double adj (heterojunction or hetero-junction)) and "257"/\$6.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 12:36
S76	2	("6150672").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/31 11:47

EAST Search History

S77	4	(single adj (heterojunction or hetero-junction)).ti,ab. and (double adj (heterojunction or hetero-junction)) and "257"/\$6.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 13:07
S78	2	("6150672").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/05/31 13:41
S79	1	(lattice near6 (match\$3 or mismatch\$3)) near12 (boron adj phosphide or BP or BPN or "BP.sub. 1-x.N.sub.x") near12 (GaN or gallium adj nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 15:47
S80	1	(lattice near6 (match\$3 or mismatch\$3)) near12 (boron adj phosphide or BP or BPN or "BP.sub. 1-x.N.sub.x") near12 (GaN or gallium adj nitride or AlGaN or aluminum adj gallium adj nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 13:44
S81	29	((boron adj phosphide or bp) near12 buffer) near12 (N or nitrogen)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 14:11
S82	1	(lattice near6 (match\$3 or mismatch\$3)) near12 (boron adj phosphide or BP or BPN or "BP.sub. 1-x.N.sub.x") near12 (GaN or gallium adj nitride or gallium adj nitride adj phosphide or GaNP)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 15:59
S83	1	(lattice near6 (match\$3 or mismatch\$3) or lattice-match\$3 or lattice-mismatch\$3) near12 (boron adj phosphide or BP or BPN or "BP.sub. 1-x.N.sub.x") near12 (GaN or gallium adj nitride or gallium adj nitride adj phosphide or GaNP)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 16:16
S84	1	(lattice near6 (match\$3 or mismatch\$3) or lattice-match\$3 or lattice-mismatch\$3) near12 (boron adj phosphide or BP or BPN or "BP.sub. 1-x.N.sub.x" or BNP or "BN.sub.1-x.P. sub.x") near12 (GaN or gallium adj nitride or gallium adj nitride adj phosphide or GaNP)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 16:33

EAST Search History

S85	66	(boron adj phosphide or BP or BPN or "BP.sub.1-x.N.sub.x" or BNP or "BN.sub.1-x.P.sub.x") near12 (GaN or gallium adj nitride or gallium adj nitride adj phosphide or GaNP)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/05/31 17:58
S86	0	"10-066769"	JPO	OR	ON	2002/05/31 17:59
S87	1	jp-10066769\$-\$.did.	JPO	OR	ON	2002/05/31 18:00
S88	1	jp-10180921\$-\$.did.	JPO	OR	ON	2002/05/31 18:01
S89	0	jp-410180921\$-\$.did.	JPO	OR	ON	2002/05/31 18:01
S90	0	terashima.in. and semiconductor	JPO	OR	ON	2002/05/31 18:12
S91	2	terashima.in. and "1998"	JPO	OR	ON	2002/05/31 18:14
S92	1	jp-10066769\$-\$.did.	JPO	OR	ON	2002/05/31 18:15
S93	1	jp-10180921\$-\$.did.	JPO	OR	ON	2002/05/31 18:16
S94	1	jp-10193125\$-\$.did.	JPO	OR	ON	2002/05/31 18:17
S95	1	jp-10232279\$-\$.did.	JPO	OR	ON	2002/05/31 18:17
S96	1	jp-11036830\$-\$.did.	JPO	OR	ON	2002/05/31 18:18
S97	2301	udagawa.in.	JPO	OR	ON	2002/05/31 18:18
S98	35	udagawa.in. and light-emitting	JPO	OR	ON	2002/05/31 18:18
S99	3	udagawa.in. and light-emitting and (BP or boron adj phosphide)	JPO	OR	ON	2002/05/31 18:22
S10 0	0	terashima.in. and light-emitting and (BP or boron adj phosphide)	JPO	OR	ON	2002/05/31 18:23
S10 1	0	nishimura.in. and light-emitting and (BP or boron adj phosphide)	JPO	OR	ON	2002/05/31 18:23
S10 2	0	tsuzaki.in. and light-emitting and (BP or boron adj phosphide)	JPO	OR	ON	2002/05/31 18:23
S10 3	11550	boron adj phosphide or bp	DERWENT	OR	ON	2002/05/31 18:25
S10 4	245	(boron adj phosphide or bp) and buffer	DERWENT	OR	ON	2002/05/31 18:25
S10 5	15	(boron adj phosphide or bp) and buffer adj layer	DERWENT	OR	ON	2002/05/31 18:25
S10 6	62	udagawa.in. and light-emitting	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 10:52
S10 7	1076	udagawa.in. and light-emitting and buffer near6 BP or BNP or BPN or "BN.sub.1-x.P.sub.x" or "BP.sub.x.N.sub.1-x" or "BN.sub.x.P.sub.1-x" or "BP.sub.1-x.N.sub.x" or ((BP or boron adj phosphide) near3 nitrogen)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 10:56

EAST Search History

S10 8	8	udagawa.in. and light-emitting and (buffer near6 (BP or BNP or BPN or "BN.sub.1-x.P.sub.x" or "BP.sub.x.N.sub.1-x" or "BN.sub.x.P.sub.1-x" or "BP.sub.1-x.N.sub.x" or ((BP or boron adj phosphide) near3 nitrogen)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 11:22
S10 9	2	terashima.in. and light-emitting and (buffer near6 (BP or BNP or BPN or "BN.sub.1-x.P.sub.x" or "BP.sub.x.N.sub.1-x" or "BN.sub.x.P.sub.1-x" or "BP.sub.1-x.N.sub.x" or ((BP or boron adj phosphide) near3 nitrogen)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 13:29
S11 0	9	light-emitting.ti,ab. and (buffer near6 (BP or BN or BNP or BPN or "BN.sub.1-x.P.sub.x" or "BP.sub.x.N.sub.1-x" or "BN.sub.x.P.sub.1-x" or "BP.sub.1-x.N.sub.x"))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 13:35
S11 1	0	(lattice adj match\$3 or mismatch\$3) and (((BN or boron adj nitride) near3 buffer) near10 (phosphorus or P)) and (GaN or gallium adj nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 13:39
S11 2	0	(lattice adj match\$3 or mismatch\$3) and (((BN or boron adj nitride) near6 buffer) near10 (phosphorus or P))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 13:39
S11 3	0	(lattice adj (match\$3 or mismatch\$3)) and (((BN or boron adj nitride) near6 buffer) near10 (phosphorus or P))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 13:40
S11 4	0	(lattice adj (match\$3 or mismatch\$3)) and (((BN or BNP or BPN or boron adj nitride) near6 buffer) near10 (phosphorus or P))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 13:41
S11 5	0	(lattice near6 (match\$3 or mismatch\$3)) and (((BN or BNP or BPN or boron adj nitride) near6 buffer) near10 (phosphorus or P))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 13:42
S11 6	672	(boron adj nitride or BN or boron adj phosphide or BP or BNP) near6 buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 13:43

EAST Search History

S11 7	99	(boron adj nitride or BN or boron adj phosphide or BP or BNP) near6 buffer and (GaN or gallium nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 14:48
S11 8	54	(boron adj nitride or BN or BNP) near6 buffer and (GaN or gallium nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 14:50
S11 9	16	(boron adj nitride or BN or BNP) near6 buffer and (GaN or gallium nitride) and (lattice-mismatch or lattice-match\$3 or (lattice near3 (match\$3 or mismatch\$3)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 14:52
S12 0	15	(boron adj nitride or BN or BNP) near6 buffer and (GaN or gallium nitride) near12 (lattice-mismatch or lattice-match\$3 or (lattice near3 (match\$3 or mismatch\$3)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 15:39
S12 1	0	gallium adj nitride adj phosphide and light-emitting.ti,ab. and phosphorus	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 15:40
S12 2	7	(GaNP or "GaN.sub.1-x.P.sub.x" or gallium adj nitride adj phosphide) and light-emitting.ti,ab. and (phosphorus or P)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 15:42
S12 3	0	(GaNP or "GaN.sub.1-x.P.sub.x" or gallium adj nitride adj phosphide) and light-emitting.ti,ab. and phosphorus	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 15:43
S12 4	2	(GaNP or "GaN.sub.1-x.P.sub.x" or gallium adj nitride adj phosphide) and light-emitting.ti,ab. and phosphorus	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 17:21
S12 5	2	lamp.ti,ab. and light-emitting.ti,ab. and semiconductor.ti,ab. and group adj "III-V"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 17:23
S12 6	6	lamp.ti,ab. and light-emitting.ti,ab. and semiconductor.ti,ab. and GaN	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 17:31

EAST Search History

S12 7	8	lamp.ti,ab. and light-emitting.ti,ab. and GaN	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 17:31
S12 8	3	lamp.ti,ab. and light-emitting.ti,ab. and GaN and mount\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 18:57
S12 9	4	((("5042043") or ("6372356") or ("5612551") or ("5326424")).PN.	USPAT; USOCR	OR	OFF	2002/06/01 19:01
S13 0	7496	((257/79) or (257/85) or (257/86) or (257/94) or (257/102) or (257/103) or (372/43)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/06/01 19:23
S13 1	3	((((257/79) or (257/85) or (257/86) or (257/94) or (257/102) or (257/103) or (372/43)).CCLS.) and (gallium adj nitride or gallium adj phosphide or GaN or GaP or "GaN.sub.1-x.P.sub.x" or "GaN.sub.x.P.sub.1-x") and buffer near4 (BN or BP or BNP or BPN or "BN.sub.x.P.1-x" or "BN.sub.1-x.P.sub. x" or boron adj nitride or boron adj phosphide) and (lattice near12 (match\$3 or mismatch\$3) or lattice-match\$3 or lattice-mismatch\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/06/01 19:28
S13 2	2	("5042043").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/11/10 14:02
S13 3	21	(US-6392257-\$ or US-5326424-\$ or US-6069021-\$ or US-6316793-\$ or US-6150672-\$ or US-5612551-\$ or US-5929467-\$ or US-5042043-\$ or US-6194744-\$ or US-6064082-\$).did. or (US-20020038892-\$ or US-20020030246-\$ or US-20020000563-\$).did. or (JP-11045892-\$ or JP-10242567-\$ or JP-10242514-\$ or JP-10242569-\$).did. or (JP-2000332294-\$ or JP-2000004046-\$ or JP-2000188260-\$ or EP-395392-\$).did.	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2002/11/10 14:08

EAST Search History

S13 4	13	((US-6392257-\$ or US-5326424-\$ or US-6069021-\$ or US-6316793-\$ or US-6150672-\$ or US-5612551-\$ or US-5929467-\$ or US-5042043-\$ or US-6194744-\$ or US-6064082-\$).did. or (US-20020038892-\$ or US-20020030246-\$ or US-20020000563-\$).did. or (JP-11045892-\$ or JP-10242567-\$ or JP-10242514-\$ or JP-10242569-\$).did. or (JP-2000332294-\$ or JP-2000004046-\$ or JP-2000188260-\$ or EP-395392-\$).did.) and (amorphous or crytalline or crystal) near12 (boron adj phosphide or bp or buffer or current-blocking or current adj blocking)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/11/10 14:09
S13 5	13	((US-6392257-\$ or US-5326424-\$ or US-6069021-\$ or US-6316793-\$ or US-6150672-\$ or US-5612551-\$ or US-5929467-\$ or US-5042043-\$ or US-6194744-\$ or US-6064082-\$).did. or (US-20020038892-\$ or US-20020030246-\$ or US-20020000563-\$).did. or (JP-11045892-\$ or JP-10242567-\$ or JP-10242514-\$ or JP-10242569-\$).did. or (JP-2000332294-\$ or JP-2000004046-\$ or JP-2000188260-\$ or EP-395392-\$).did.) and (amorphous or crystalline or crystal) near12 (boron adj phosphide or bp or buffer or current-blocking or current adj blocking)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/11/10 15:47
S13 6	212	oh.in. and won.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/11/10 15:48
S13 7	18	oh.in. and won.in. and buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/11/10 15:48
S13 8	4	oh.in. and won.in. and buffer and nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2002/11/10 16:37

EAST Search History

S13 9	2	("6069021").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2002/11/10 16:37
S14 0	2	("5042043").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2003/04/15 17:45
S14 1	344	mixed adj crystal near12 (single-crystal or single adj crystal or monocrystal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/15 17:46
S14 2	254	mixed adj crystal near6 (single-crystal or single adj crystal or monocrystal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/15 17:47
S14 3	145	mixed adj crystal near3 (single-crystal or single adj crystal or monocrystal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/15 17:47
S14 4	87	mixed adj crystal near3 (single-crystal or single adj crystal or monocrystal).ti, ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/15 17:47
S14 5	0	"GaN.sub.0.97Psub.0.03"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 09:55
S14 6	0	"Ga N.sub.0.97 P.sub.0.03"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 09:56
S14 7	0	"Ga N.sub."\$6 near2 "P.sub."\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 09:58

EAST Search History

S14 8	7	"Ga N.sub."	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 09:58
S14 9	0	"GaN.sub."	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 09:59
S15 0	94	"GaN.sub"\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 10:00
S15 1	12	"GaN.sub"\$6 and (BP or boron adj phosphide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 10:01
S15 2	0	"GaP.sub"\$6 near20 (BP or boron adj phosphide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 10:01
S15 3	4	"GaN.sub"\$6 near20 (BP or boron adj phosphide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 10:04
S15 4	2	"GaN.sub"\$6 near20 buffer and (BP or boron adj phosphide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 10:05
S15 5	1024	mixed adj crystal.ti.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 10:06
S15 6	103	mixed adj crystal.ti. and (single-crystal or single adj crystal or single-crystalline or single adj crystalline or monocrystal or monocrystalline)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 11:27
S15 7	2	lattice adj match\$3 near20 (boron adj phosphide or BP) near20 (gallium adj nitride or GaN)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 11:28

EAST Search History

S15 8	2	(lattice-match\$3 lattice adj match\$3) near20 (boron adj phosphide or BP) near20 (gallium adj nitride or GaN)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 11:36
S15 9	86	(gan or gallium adj nitride) near20 (boron adj phosphide or bp)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 11:37
S16 0	13	(gan or gallium adj nitride) near20 (boron adj phosphide or bp) near20 buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 12:35
S16 1	173	(gan or gallium adj nitride) near20 lattice adj constant	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 13:39
S16 2	11	(gan or gallium adj nitride) near20 buffer adj layer near20 (boron adj phosphide or bp)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 13:40
S16 3	5	(single-crystal or single adj crystal or monocrystalline) near20 (gan or gallium adj nitride) near20 buffer adj layer near20 (boron adj phosphide or bp)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 13:47
S16 4	556	(vapor adj phase adj growth or CVD) near3 (single-crystal or single adj crystal or monocrystal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 13:56
S16 5	192	(vapor adj phase adj growth or CVD) near3 (single-crystal or single adj crystal or monocrystal).ti,ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 14:37
S16 6	1	increase near12 lattice adj parameter near12 (phosphorous or phosphorus)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/16 15:52

EAST Search History

S16 7	2	("5042043").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2003/04/16 15:52
S16 8	2	("6069021").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2003/10/22 19:01
S16 9	2	("6069021").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2003/10/23 19:10
S17 0	0	((latticeadjmatchinglatticeadjmismatch)and257/79.ccls.257/8\$1.ccls.257/9\$1. ccls.257/100.ccls.257/101.ccls. 257/102.ccls.257/103.ccls.)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2003/10/23 19:12
S17 1	359	(lattice adj matching lattice adj mismatch) and (257/79.ccls. 257/8\$1. ccls. 257/9\$1.ccls. 257/100.ccls. 257/101.ccls. 257/102.ccls. 257/103. ccls.)	USPAT	OR	OFF	2003/10/23 19:13
S17 2	20	(lattice adj matching lattice adj mismatch).ti,ab,clm. and group adj III and (257/79.ccls. 257/8\$1.ccls. 257/9\$1.ccls. 257/100.ccls. 257/101. ccls. 257/102.ccls. 257/103.ccls.)	USPAT	OR	OFF	2003/10/23 19:13
S17 3	4447	((257/79) or (257/80) or (257/81) or (257/82) or (257/83) or (257/84) or (257/85) or (257/86) or (257/86) or (257/87) or (257/88) or (257/89) or (257/90) or (257/91) or (257/92) or (257/93) or (257/94) or (257/95) or (257/96) or (257/97) or (257/98) or (257/99) or (257/100) or (257/101) or (257/102) or (257/103)).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2003/11/03 11:30

EAST Search History

S17 4	8	((257/79) or (257/80) or (257/81) or (257/82) or (257/83) or (257/84) or (257/85) or (257/86) or (257/86) or (257/87) or (257/88) or (257/89) or (257/90) or (257/91) or (257/92) or (257/93) or (257/94) or (257/95) or (257/96) or (257/97) or (257/98) or (257/99) or (257/100) or (257/101) or (257/102) or (257/103)).CCLS.) and (GaNP GaPN gallium adj phosphide adj nitride) and cubic	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2003/11/03 11:32
S17 5	5	"885943".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 13:33
S17 6	6	"753393".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/28 13:57
S17 7	11	(("6069021") or ("5042043") or ("5326424") or ("6121637") or ("5612551")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/28 13:58
S17 8	55	buffer adj layer near4 (boron adj phosphide BP BP-based boron adj nitride adj phosphide boron adj phosphide adj nitride "BN.sub."\$2"P.sub."\$2 "BP.sub."\$2"N.sub."\$2) and (laser light-emitting light adj emitting). ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/28 15:28
S17 9	17	buffer adj layer near4 (boron adj phosphide BP BP-based boron adj nitride adj phosphide boron adj phosphide adj nitride "BN.sub."\$3"P.sub."\$3 "BP.sub."\$3"N.sub."\$3) and (laser light-emitting light adj emitting). ti,ab,clm. and single adj crystal adj substrate and (gallium adj nitride adj phosphide "GaN.sub."\$3"P.sub."\$3 "GaP.sub."\$3"N.sub."\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/28 17:39

EAST Search History

S18 0	19	buffer adj layer near4 (boron adj phosphide BP BP-based boron adj nitride adj phosphide boron adj phosphide adj nitride "BN.sub."\$3"P.sub."\$3 "BP.sub."\$3"N.sub."\$3) and (laser light-emitting light adj emitting).ti,ab,clm. and (gallium adj nitride adj phosphide "GaN.sub."\$3"P.sub."\$3 "GaP.sub."\$3"N.sub."\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/28 16:56
S18 1	2	(buffer adj layer near4 (boron adj phosphide BP BP-based boron adj nitride adj phosphide boron adj phosphide adj nitride "BN.sub."\$3"P.sub."\$3 "BP.sub."\$3"N.sub."\$3) and (laser light-emitting light adj emitting).ti,ab,clm. and (gallium adj nitride adj phosphide "GaN.sub."\$3"P.sub."\$3 "GaP.sub."\$3"N.sub."\$3)) not (buffer adj layer near4 (boron adj phosphide BP BP-based boron adj nitride adj phosphide boron adj phosphide adj nitride "BN.sub."\$3"P.sub."\$3 "BP.sub."\$3"N.sub."\$3) and (laser light-emitting light adj emitting).ti,ab,clm. and single adj crystal adj substrate and (gallium adj nitride adj phosphide "GaN.sub."\$3"P.sub."\$3 "GaP.sub."\$3"N.sub."\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/28 16:23
S18 2	36	(US-6787814-\$ or US-6541799-\$ or US-6150672-\$ or US-6316793-\$ or US-6069021-\$ or US-6064082-\$ or US-5929467-\$ or US-5042043-\$ or US-6194744-\$ or US-5326424-\$ or US-6392257-\$ or US-5612551-\$ or US-6730941-\$ or US-6797990-\$).did. or (US-20020000563-\$ or US-20010054717-\$ or US-20030178631-\$ or US-20020030246-\$ or US-20020038892-\$ or US-20020113235-\$ or US-20030001162-\$ or US-20030027099-\$ or US-20030141509-\$ or US-20030173573-\$ or US-20030160253-\$).did. or (JP-10242514-\$ or JP-10242567-\$ or JP-11199397-\$ or JP-11045892-\$ or JP-2002009340-\$ or JP-10242569-\$).did. or (EP-395392-\$ or US-20010054717-\$ or JP-2000332294-\$ or JP-2000188260-\$ or JP-2000004046-\$).did.	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2004/09/28 16:25

EAST Search History

S18 3	19	buffer near4 (boron adj phosphide BP BP-based boron adj nitride adj phosphide boron adj phosphide adj nitride "BN.sub."\$3"P.sub."\$3 "BP.sub."\$3"N.sub."\$3) and (laser light-emitting light adj emitting).ti,ab, clm. and (gallium adj nitride adj phosphide "GaN.sub."\$3"P.sub."\$3 "GaP.sub."\$3"N.sub."\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/28 17:13
S18 4	432	buffer near4 (boron adj phosphide BP BP-based boron adj nitride adj phosphide boron adj phosphide adj nitride "BN.sub."\$3"P.sub."\$3 "BP.sub."\$3"N.sub."\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/28 17:13
S18 5	110	buffer near4 (boron adj phosphide BP BP-based boron adj nitride adj phosphide boron adj phosphide adj nitride "BN.sub."\$3"P.sub."\$3 "BP.sub."\$3"N.sub."\$3) and (laser light-emitting light adj emitting)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/28 17:14
S18 6	9	buffer near4 (boron adj phosphide BP BP-based boron adj nitride adj phosphide boron adj phosphide adj nitride "BN.sub."\$3"P.sub."\$3 "BP.sub."\$3"N.sub."\$3) and (laser light-emitting light adj emitting) and (GaInN GaNP GaPN)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/28 17:15
S18 7	2	("6194744").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/28 17:39

EAST Search History

S18 8	36	(US-5042043-\$ or US-6194744-\$ or US-6069021-\$ or US-6316793-\$ or US-6150672-\$ or US-6392257-\$ or US-5326424-\$ or US-6064082-\$ or US-5929467-\$ or US-6541799-\$ or US-6787814-\$ or US-6797990-\$ or US-6730941-\$ or US-5612551-\$).did. or (US-20010054717-\$ or US-20020000563-\$ or US-20020030246-\$ or US-20030027099-\$ or US-20020113235-\$ or US-20030001162-\$ or US-20030178631-\$ or US-20030141509-\$ or US-20030173573-\$ or US-20030160253-\$ or US-20020038892-\$).did. or (JP-2002009340-\$ or JP-10242514-\$ or JP-10242567-\$ or JP-11199397-\$ or JP-10242569-\$ or JP-11045892-\$).did. or (US-20010054717-\$ or EP-395392-\$ or JP-2000332294-\$ or JP-2000004046-\$ or JP-2000188260-\$).did.	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2004/09/29 09:59
S18 9	30	(light adj emitting active) near4 (gallium adj nitride adj phosphide gallium adj phosphide adj nitride GaNP GaPN "Ga.sub."\$3"N.sub."\$3"P.sub."\$3 "Ga.sub."\$3"N.sub."\$3"P.sub."\$3)	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2004/09/29 10:02
S19 0	7	(light adj emitting active) near4 (gallium adj nitride adj phosphide gallium adj phosphide adj nitride GaNP GaPN "Ga.sub."\$3"N.sub."\$3"P.sub."\$3 "Ga.sub."\$3"N.sub."\$3"P.sub."\$3) and buffer near4 (BP BPN BNP boron)	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2004/09/29 10:13
S19 1	285	UDAGAWA.IN. AND (light adj emitting laser)	JPO; DERWENT	OR	OFF	2004/09/29 10:14
S19 2	122	takashi near2 udagawa.in. and (light adj emitting laser)	JPO; DERWENT	OR	OFF	2004/09/29 10:14
S19 3	122	takashi near2 udagawa.in. and (light adj emitting laser).ti,ab,clm.	JPO; DERWENT	OR	OFF	2004/09/29 10:30
S19 4	0	takashi near2 udagawa.in.	DERWENT	OR	OFF	2004/09/29 10:30
S19 5	27726	showa.as.	DERWENT	OR	OFF	2004/09/29 10:30
S19 6	524	showa.as. and (light adj emitting laser).ti,ab.	DERWENT	OR	OFF	2004/09/29 10:31
S19 7	48	showa.as. and (light adj emitting laser).ti,ab. and buffer.ti,ab.	DERWENT	OR	OFF	2004/09/29 10:42

EAST Search History

S19 8	0	amorphous near4 (low adj tempetaure LT) near4 buffer near12 (boron BP BNP BPN)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 10:43
S19 9	0	(low adj tempetaure LT) near4 buffer near12 (boron BP BNP BPN)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 10:44
S20 0	27	(low adj temperature LT) near4 buffer near12 (boron BP BNP BPN)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 11:19
S20 1	2	("5789768").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 11:31
S20 2	0	((("5789768").PN.) and buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 11:22
S20 3	0	((("5789768").PN.) and boron	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 11:22
S20 4	0	BP and ((("5789768").PN.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 11:22
S20 5	48	buffer and udagawa.in. and (BP boron) near4 buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 11:35
S20 6	0	("udagawa.in.and(baumeister.xa.baumeister.xp.)").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 11:31

EAST Search History

S20 7	0	udagawa.in. and (baumeister.xa. baumeister.xp.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 11:31
S20 8	5	"885943".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 14:51
S20 9	2	"20030173573"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 11:40
S21 0	22	buffer near4 (boron BP B-based BP-based).clm. and (light-emitting laser light adj emitting)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 11:41
S21 1	3	buffer near4 (boron BP B-based BP-based).clm. and (light-emitting laser light adj emitting) and ("GaN. sub.1-x"\$3"P.sub."\$3 "GaN.sub. x"\$3"P.sub.1-x"\$3).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 11:53
S21 2	2	("6079064").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 11:53
S21 3	2	("6078064").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 11:54
S21 4	2	("5789768").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 11:55
S21 5	2	("5076860").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 12:09

EAST Search History

S21 6	7	"GaN.sub."\$3"P.sub."\$3 near4 (active clad cladding light-emitting light adj emitting)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 12:11
S21 7	38	(gallium adj nitride adj phosphide gallium adj phosphide adj nitride GANP GAPN "GaN.sub."\$3"P.sub."\$3) near4 (active clad cladding light-emitting light adj emitting)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 12:20
S21 8	10	(gallium adj nitride adj phosphide gallium adj phosphide adj nitride GANP GAPN "GaN.sub."\$3"P.sub."\$3) near4 (clad cladding)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 13:19
S21 9	5	((gallium adj nitride adj phosphide gallium adj phosphide adj nitride GANP GAPN "GaN.sub."\$3"P.sub."\$3) near4 (clad cladding)) not udagawa.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 13:45
S22 0	4	("6233264").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 13:33
S22 1	1	jp-05141750\$-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 13:46
S22 2	1	kondo.in. and lattice adj distortion.ti, ab,clm. and epitaxially	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 14:25
S22 3	9	buffer near5 boron adj phosphide and "GaN.sub."\$3"P.sub."\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 18:15
S22 4	10	buffer near5 (BP BP-based BPN BNP "BP.sub."\$3 "BN.sub."\$3"P.sub."\$3 boron adj phosphide) and "GaN.sub."\$3"P.sub."\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 14:28

EAST Search History

S22 5	13	((("5042043") or ("6372356") or ("5612551") or ("6121637") or ("5326424") or ("6069021"))).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 14:59
S22 6	3	"090344".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 14:59
S22 7	10	buffer near5 (BP BNP BPN "B.sub. "\$3"P.sub."\$3 "B.sub."\$3"P.sub."\$3 boron adj phosphide) and "GaN.sub. "\$3"P.sub."\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/29 18:16
S22 8	4	(boron adj phosphide BP BNP BPN "BN.sub."\$3"P.sub."\$3 "BP.sub."\$3"N. sub."\$3) near12 ("GaP.sub."\$3"N.sub. "\$3 "GaN.sub."\$3"P.sub."\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 08:01
S22 9	2	(boron adj phosphide BP BNP BPN "BN.sub."\$3"P.sub."\$3 "BP.sub."\$3"N. sub."\$3 boron) near4 buffer near12 ("GaP.sub."\$3"N.sub."\$3 "GaN.sub. "\$3"P.sub."\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 08:02
S23 0	11	(boron adj phosphide BP BNP BPN "BN.sub."\$3"P.sub."\$3 "BP.sub."\$3"N. sub."\$3 boron) near4 buffer and ("GaP.sub."\$3"N.sub."\$3 "GaN.sub. "\$3"P.sub."\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 08:03
S23 1	597	(boron adj phosphide BP BNP BPN "BN.sub."\$3"P.sub."\$3 "BP.sub."\$3"N. sub."\$3 boron) near4 buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 08:04
S23 2	160	(boron adj phosphide BP BNP BPN "BN.sub."\$3"P.sub."\$3 "BP.sub."\$3"N. sub."\$3 boron) near4 buffer.ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 08:04
S23 3	123	(boron adj phosphide BP BNP BPN "BN.sub."\$3"P.sub."\$3 "BP.sub."\$3"N. sub."\$3 boron) near4 buffer.ti,ab,clm. not udagawa.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 08:39

EAST Search History

S23 4	5	"885943".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 10:26
S23 5	949	mixed adj crystal.ti.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 10:26
S23 6	113	mixed adj crystal.ti. and laser.ti.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 10:26
S23 7	40	mixed adj crystal.ti. and laser.ti. and (active light-emitting).ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 11:24
S23 8	2	(single adj heterojunction single adj heterostructure SH) and buffer and GaNP and GaInP	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 11:25
S23 9	2	(single adj heterojunction single adj heterostructure SH) and buffer and (gallium adj nitride adj phosphide GaNP gallium adj phosphide adj nitride GaPN "Ga.N.sub."\$3"P.sub."\$3 "Ga.P. sub."\$3"N.sub."\$3) and GaInP	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 11:28
S24 0	13	(single adj heterojunction single adj heterostructure SH) and buffer and (gallium adj nitride adj phosphide GaNP gallium adj phosphide adj nitride GaPN "Ga.N.sub."\$3"P.sub."\$3 "Ga.P. sub."\$3"N.sub."\$3) and (gallium adj indium adj nitride GaInN "GaIn.sub. "\$3"N.sub."\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 11:30
S24 1	37	buffer and (gallium adj nitride adj phosphide GaNP gallium adj phosphide adj nitride GaPN "Ga.N.sub. "\$3"P.sub."\$3 "Ga.P.sub."\$3"N.sub. "\$3) and (gallium adj indium adj nitride GaInN "GaIn.sub."\$3"N.sub. "\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 11:33

EAST Search History

S24 2	3	buffer and (gallium adj nitride adj phosphide GaNP gallium adj phosphide adj nitride GaPN "Ga.N.sub."\$3"P.sub."\$3 "Ga.P.sub."\$3"N.sub."\$3) near6 (clad cladding) and (gallium adj indium adj nitride GaInN "GaIn.sub."\$3"N.sub."\$3) near6 (active light-emitting light adj emitting)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 11:35
S24 3	3	(gallium adj nitride adj phosphide GaNP gallium adj phosphide adj nitride GaPN "Ga.N.sub."\$3"P.sub."\$3 "Ga.P.sub."\$3"N.sub."\$3) near6 (clad cladding) and (gallium adj indium adj nitride GaInN "GaIn.sub."\$3"N.sub."\$3) near6 (active light-emitting light adj emitting)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 11:35
S24 4	34	buffer and (gallium adj nitride adj phosphide GaNP gallium adj phosphide adj nitride GaPN "Ga.N.sub."\$3"P.sub."\$3 "Ga.P.sub."\$3"N.sub."\$3) and (gallium adj indium adj nitride GaInN "GaIn.sub."\$3"N.sub."\$3) and (clad cladding)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 11:35
S24 5	19	(buffer and (gallium adj nitride adj phosphide GaNP gallium adj phosphide adj nitride GaPN "Ga.N.sub."\$3"P.sub."\$3 "Ga.P.sub."\$3"N.sub."\$3) and (gallium adj indium adj nitride GaInN "GaIn.sub."\$3"N.sub."\$3) and (clad cladding)) not udagawa.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 11:38
S24 6	3	(buffer and (gallium adj nitride adj phosphide GaNP gallium adj phosphide adj nitride GaPN "Ga.N.sub."\$3"P.sub."\$3 "Ga.P.sub."\$3"N.sub."\$3) and (gallium adj indium adj nitride GaInN "GaIn.sub."\$3"N.sub."\$3) near6 (clad cladding)) not udagawa.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 11:49
S24 7	2	("5042043").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 11:49
S24 8	0	((("5042043").PN.) and indium	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:44

EAST Search History

S249	31	alumin\$um adj free same indium	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 11:50
S250	5	alumin\$um adj free same indium and (light-emitting light adj emitting)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 11:54
S251	1971	(InN GaN) near4 (active light-emitting light adj emitting)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 11:56
S252	5	(InN GaN) near4 (active light-emitting light adj emitting) and (GaNP GaPN "GaN.sub."\$3"P.sub."\$3 "GaP.sub."\$3"N.sub."\$3 gallium adj nitride adj phosphide gallium adj phosphide adj nitride) near4 (clad cladding)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 12:00
S253	7	(boron adj phosphide BP) near4 buffer and GaN near4 (light-emitting active light adj emitting) and GaN near4 (clad cladding)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 12:46
S254	2	lattice adj constant near4 "GaN.sub."\$3"P.sub."\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 12:47
S255	36	"5042043"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 13:35
S256	6	((("5042043") or ("6372356") or ("5612551") or ("6121637") or ("5326424") or ("6069021"))).PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2004/09/30 13:38
S257	7	jp-10242514\$-\$\$.did. jp-10242567\$-\$\$.did. jp-10242569\$-\$\$.did. jp-11045892\$-\$\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 13:55
S258	13	((("5042043") or ("6372356") or ("5612551") or ("6121637") or ("5326424") or ("6069021"))).PN.) (jp-10242514\$-\$\$.did. jp-10242567\$-\$\$.did. jp-10242569\$-\$\$.did. jp-11045892\$-\$\$.did.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:17

EAST Search History

S25 9	13	((("5042043") or ("6372356") or ("5612551") or ("6121637") or ("5326424") or ("6069021")).PN.) (jp-10242514\$-\$\$.did. jp-10242567\$-\$\$.did. jp-10242569\$-\$\$.did. jp-11045892\$-\$\$.did.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:17
S26 0	22827	257/79.ccls. 257/8\$1.ccls. 257/9\$1.ccls. 257/100.ccls. 257/101.ccls. 257/103.ccls. 372/4\$1.ccls. 372/50.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:19
S26 1	13	(257/79.ccls. 257/8\$1.ccls. 257/9\$1.ccls. 257/100.ccls. 257/101.ccls. 257/103.ccls. 372/4\$1.ccls. 372/50.ccls.) and boron near4 buffer and gallium adj2 nitride and lattice near2 match\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:30
S26 2	12	advantage near4 phosphorus near12 (dopant doping)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:32
S26 3	0	advantage near4 phosphorus near12 (dopant doping) same GaN same (clad cladding)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:33
S26 4	145	n-type adj GaN near4 (clad cladding) adj layer same (P phosphor\$us)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:34
S26 5	121	n-type adj GaN near4 (clad cladding) adj layer same (P phosphor\$us) and (light-emitting light adj emitting laser). ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:34
S26 6	16	n-type adj GaN near4 (clad cladding) adj layer near4 (P phosphor\$us) and (light-emitting light adj emitting laser). ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:36
S26 7	0	n-type adj GaN near4 (clad cladding) adj layer near4 (phosphor\$us phosphor) and (light-emitting light adj emitting laser).ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:37

EAST Search History

S26 8	0	n-type adj GaN near4 (clad cladding) adj layer near4 dopant and (light-emitting light adj emitting laser). ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 14:37
S26 9	0	n-type adj GaN near4 (clad cladding) adj layer near4 dopant	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 14:38
S27 0	0	(n-GaN n-type adj GaN) near4 (clad cladding) adj layer near4 dopant	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 14:38
S27 1	22	(n-GaN n-type adj GaN) near4 (clad cladding) adj layer near4 (doped impurities dopant)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 14:38
S27 2	27	"6069021"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:46
S27 3	2	("6069021").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:47
S27 4	1	"4293370".PN.	USPAT	OR	OFF	2004/09/30 14:47
S27 5	0	("GaNnear4N-dopednear4Pandlightadj emitting.ti,ab,clm.").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:48
S27 6	9	GaN near4 N-doped near4 P and light adj emitting.ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:51
S27 7	11	(gallium adj nitride GaN) near4 N-doped near4 P and light adj emitting.ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:52

EAST Search History

S27 8	0	(gallium adj nitride GaN) near4 "doped with P" and light adj emitting.ti,ab, clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:52
S27 9	0	(gallium adj nitride GaN) near4 "doped with P"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:53
S28 0	0	(gallium adj nitride GaN) near6 "doped with P"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:53
S28 1	0	(gallium adj nitride GaN) near6 "doped with phosphorus"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:53
S28 2	0	(gallium adj nitride GaN) near6 "doped with phosphorous"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:53
S28 3	2	(gallium adj nitride GaN) adj layer near4 doped same (phosphorous phosphorus phosphor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 15:09
S28 4	2	(gallium adj nitride GaN) adj layer near4 (doping doped) same (phosphorous phosphorus phosphor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:56
S28 5	10	(gallium adj nitride GaN) adj layer near4 (n-type doping doped) same (phosphorous phosphorus phosphor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 14:56
S28 6	9	(gallium adj nitride GaN) adj layer near4 n-type same (phosphorous phosphorus phosphor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 15:11
S28 7	795	(gallium adj nitride GaN) adj layer near4 n-type same ("P" phosphorous phosphorus phosphor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 15:12

EAST Search History

S28 8	287	(gallium adj nitride GaN) adj layer near4 n-type near4 ("P" phosphorous phosphorus phosphor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 15:27
S28 9	21	(gallium adj nitride GaN) adj layer near4 n-type near4 ("P" phosphorous phosphorus phosphor) and (phosporous phosphorus)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 15:28
S29 6	12	jp-05283744\$-\$.did. jp-11266006\$-\$.did. jp-02288388\$-\$.did. jp-08064870\$-\$.did. jp-08236810\$-\$.did. jp-2000012896\$-\$.did. jp-20000311614\$-\$.did.	JPO; DERWENT	OR	OFF	2005/03/09 06:21
S29 7	14	jp-05283744\$-\$.did. jp-11266006\$-\$.did. jp-02288388\$-\$.did. jp-08064870\$-\$.did. jp-08236810\$-\$.did. jp-2000012896\$-\$.did. jp-2000031164\$-\$.did.	JPO; DERWENT	OR	OFF	2005/03/09 06:21
S29 8	26	(US-6121637-\$ or US-6069021-\$ or US-5042043-\$ or US-6372356-\$ or US-5612551-\$ or US-5326424-\$).did. or (JP-11045892-\$ or JP-10242514-\$ or JP-10242567-\$ or JP-10242569-\$ or JP-11266006-\$ or JP-02288388-\$ or JP-05283744-\$ or JP-08064870-\$ or JP-2000012896-\$ or JP-08236810-\$ or JP-2000031164-\$).did. or (JP-11045892-\$ or EP-395392-\$ or JP-10242514-\$ or JP-05283744-\$ or JP-08064870-\$ or JP-2000012896-\$ or JP-08236810-\$ or JP-2000031164-\$ or JP-11266006-\$).did.	USPAT; JPO; DERWENT	OR	OFF	2005/03/09 06:24
S29 9	26	(US-6121637-\$ or US-6069021-\$ or US-5042043-\$ or US-6372356-\$ or US-5612551-\$ or US-5326424-\$).did. or (JP-11045892-\$ or JP-10242514-\$ or JP-10242567-\$ or JP-10242569-\$ or JP-11266006-\$ or JP-02288388-\$ or JP-05283744-\$ or JP-08064870-\$ or JP-2000012896-\$ or JP-08236810-\$ or JP-2000031164-\$).did. or (JP-11045892-\$ or EP-395392-\$ or JP-10242514-\$ or JP-05283744-\$ or JP-08064870-\$ or JP-2000012896-\$ or JP-08236810-\$ or JP-2000031164-\$ or JP-11266006-\$).did.	USPAT; JPO; DERWENT	OR	OFF	2005/03/09 07:07

EAST Search History

S30 0	2	("6069021").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/09 10:26
S30 1	6	"753393".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/09 07:56
S30 2	26	(US-6121637-\$ or US-6069021-\$ or US-5042043-\$ or US-6372356-\$ or US-5612551-\$ or US-5326424-\$).did. or (JP-11045892-\$ or JP-10242514-\$ or JP-10242567-\$ or JP-10242569-\$ or JP-11266006-\$ or JP-02288388-\$ or JP-05283744-\$ or JP-08064870-\$ or JP-2000012896-\$ or JP-08236810-\$ or JP-2000031164-\$).did. or (JP-11045892-\$ or EP-395392-\$ or JP-10242514-\$ or JP-05283744-\$ or JP-08064870-\$ or JP-2000012896-\$ or JP-08236810-\$ or JP-2000031164-\$ or JP-11266006-\$).did.	USPAT; JPO; DERWENT	OR	OFF	2005/03/09 08:12
S30 3	3	S302 and dislocation	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/09 08:13
S30 4	634	dislocation adj density and lattice adj (mismatch\$3 match\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/09 08:21
S30 5	376	dislocation adj density and lattice adj (mismatch\$3 match\$3) and (gallium adj nitride GaN)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/09 08:23
S30 6	0	S302 and dislocation adj density and lattice adj (mismatch\$3 match\$3) and (gallium adj nitride GaN)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/09 08:23
S30 7	15	dislocation adj density near6 lattice adj (mismatch\$3 match\$3) and (gallium adj nitride GaN)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/09 08:29

EAST Search History

S308	15	dislocation adj density near6 lattice adj (mismatch\$3 match\$3) and (gallium adj nitride GaN) and dislocation adj density	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/09 08:29
S309	6	(US-20040144990-\$ or US-20020086627-\$).did. or (US-5321101-\$ or US-4633280-\$ or US-4086078-\$).did. or (EP-753393-\$).did.	US-PGPUB; USPAT; DERWENT	OR	OFF	2005/03/09 09:42
S310	1	(US-20040144990-\$).did.	US-PGPUB	OR	OFF	2005/03/09 09:43
S311	0	Mg adj doped near4 ("Ga.sub."\$3"In.sub."\$3"N" and lattice adj (parameter constant))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/09 10:33
S312	0	"Ga.sub."\$3"In.sub."\$3"N" near4 lattice adj (parameter constant)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/09 10:34
S313	78	"Ga.sub."\$3"In.sub."\$3"N" and lattice adj (parameter constant)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/09 10:34
S314	6	(undoped un-doped) near3 "Ga.sub."\$3"In.sub."\$3"N" and lattice adj (parameter constant)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/09 13:10
S315	59	single adj heterostructure and (GaInGaInN) and (372/4\$1.ccls. 372/50.ccls. 257/79.ccls. 257/8\$1.ccls. 257/9\$1.ccls. 257/10\$1.ccls.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/09 13:12
S316	14	(JP-11266006-\$ or JP-02288388-\$ or JP-05283744-\$ or JP-08064870-\$ or JP-2000012896-\$ or JP-08236810-\$ or JP-2000031164-\$).did. or (JP-05283744-\$ or JP-08064870-\$ or EP-395392-\$ or JP-2000012896-\$ or JP-08236810-\$ or JP-2000031164-\$ or JP-11266006-\$).did.	JPO; DERWENT	OR	OFF	2005/03/09 15:28
S317	2	("5042043").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/09 15:35

EAST Search History

S31 8	3	("GaN.sub."\$3"P.sub."\$3 "GaP.sub." "\$3"N.sub."\$3) near4 (clad cladding) adj (layer film)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/09 16:15
S31 9	6	"885943".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/09 16:22
S32 0	13	((("5042043") or ("5326424") or ("5612551") or ("6069021") or ("6121637") or ("6372356")).PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/09 16:39
S32 1	2	("6,339,014").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/09 16:32
S32 2	0	S320 and single adj heterostructure	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/09 16:39
S32 3	0	S320 and (single adj heterostructure single-heterostructure)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/09 16:39
S32 4	0	S320 and (single adj heterostructure single-heterostructure)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/09 16:44
S32 5	310	(single adj heterostructure single-heterostructure) and (light-emitting laser light adj emitting). ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/09 16:44
S32 6	0	(single adj heterostructure single-heterostructure) and (light-emitting laser light adj emitting). ti,ab,clm. and (boron BP "BN.sub." "\$3"P.sub."\$3 "BP.sub."\$3"N.sub."\$3) near4 (buffer binding adhesive adhesion transitiona\$2 matching)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/09 16:46

EAST Search History

S32 7	72	(US-20010054717-\$ or US-20020000563-\$ or US-20020030246-\$ or US-20020038892-\$ or US-20020113235-\$ or US-20030001162-\$ or US-20030027099-\$ or US-20030047795-\$ or US-20030141509-\$ or US-20030160253-\$ or US-20030173573-\$ or US-20030178631-\$ or US-20030209714-\$ or US-20030234400-\$ or US-20040144990-\$ or US-20040169180-\$ or US-20040183089-\$).did. or (US-5042043-\$ or US-5326424-\$ or US-5612551-\$ or US-5929467-\$ or US-6064082-\$ or US-6069021-\$ or US-6078064-\$ or US-6121637-\$ or US-6150672-\$ or US-6194744-\$ or US-6266355-\$ or US-6316793-\$ or US-6339014-\$ or US-6342405-\$ or US-6372356-\$ or US-6392257-\$ or US-6541799-\$ or US-6613461-\$ or US-6730941-\$ or US-6787814-\$ or US-6797990-\$).did. or (JP-10032370-\$ or JP-10242514-\$ or JP-10242567-\$ or JP-10242569-\$ or JP-10247760-\$ or JP-11045892-\$ or JP-11199397-\$ or JP-2000058451-\$ or JP-2000150957-\$ or JP-2000174342-\$ or JP-2000235956-\$ or JP-2001320089-\$ or JP-2002009340-\$ or JP-2000012896-\$ or JP-11266006-\$ or JP-08236810-\$ or JP-08064870-\$ or JP-05283744-\$ or JP-02288388-\$ or JP-2000031164-\$).did. or (EP-395392-\$ or JP-11045892-\$ or JP-2000188260-\$ or JP-2000332294-\$ or JP-2000004046-\$ or US-20010054717-\$ or JP-2001320089-\$ or JP-2000012896-\$ or JP-11266006-\$ or JP-08236810-\$ or JP-08064870-\$ or JP-05283744-\$ or JP-2000031164-\$ or US-6069021-\$). did.	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2005/03/09 16:55
S32 8	12	S327 and (single adj heterostructure single adj hetero)	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2005/03/09 16:55

EAST Search History

S33 0	688	(GaInN InGaN "Ga.sub."\$4"In.sub." "\$4N "In.sub."\$4"Ga.sub."\$4N) near10 (active light-emitting) adj2 (layer film)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/10 07:50
S33 1	5	(GaInN InGaN "Ga.sub."\$4"In.sub." "\$4N "In.sub."\$4"Ga.sub."\$4N) near10 (active light-emitting) adj2 (layer film) and (GaNP GaPN "GaN.sub."\$4"P.sub." "\$4 "GaP.sub."\$4"N.sub."\$4) near10 (clad cladding) adj2 (layer film)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/10 11:14
S33 2	55	(GaInN InGaN "Ga.sub."\$4"In.sub." "\$4N "In.sub."\$4"Ga.sub."\$4N) near10 (active light-emitting) adj2 (layer film) and (GaNP GaPN "GaN.sub."\$4"P.sub." "\$4 "GaP.sub."\$4"N.sub."\$4 (p-doped p-type) near10 GaN) near10 (clad cladding) adj2 (layer film)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/10 07:57
S33 3	69	(GaInN InGaN "Ga.sub."\$4"In.sub." "\$4N "In.sub."\$4"Ga.sub."\$4N) near10 (active light-emitting) adj2 (layer film) and (GaNP GaPN "GaN.sub."\$4"P.sub." "\$4 "GaP.sub."\$4"N.sub."\$4 (n-doped n-type) near10 GaN) near10 (clad cladding) adj2 (layer film)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/10 07:58
S33 4	30	(GaInN InGaN "Ga.sub."\$4"In.sub." "\$4N "In.sub."\$4"Ga.sub."\$4N) near10 (active light-emitting) adj2 (layer film) and (GaNP GaPN "GaN.sub."\$4"P.sub." "\$4 "GaP.sub."\$4"N.sub."\$4 (n-doped n-type) near10 GaN) near10 (clad cladding) adj2 (layer film) and S332	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/10 07:58
S33 5	29	(GaInN InGaN "Ga.sub."\$4"In.sub." "\$4N "In.sub."\$4"Ga.sub."\$4N) near10 (active light-emitting) adj2 (layer film) and (GaNP GaPN "GaN.sub."\$4"P.sub." "\$4 "GaP.sub."\$4"N.sub."\$4 (n-doped n-type) near10 GaN) near10 (clad cladding) adj2 (layer film) and S332 and (buffer intermediate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/10 07:59
S33 6	7	(GaInN InGaN "Ga.sub."\$4"In.sub." "\$4N "In.sub."\$4"Ga.sub."\$4N) near10 (active light-emitting) adj2 (layer film) and (GaNP GaPN "GaN.sub."\$4"P.sub." "\$4 "GaP.sub."\$4"N.sub."\$4 (n-doped n-type) near10 GaN) near10 (clad cladding) adj2 (layer film) and S332 and (buffer intermediate) near10 (boron boron-based BP B)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/10 07:59

EAST Search History

S33 7	73	(US-20010054717-\$ or US-20020000563-\$ or US-20020030246-\$ or US-20020038892-\$ or US-20020113235-\$ or US-20030001162-\$ or US-20030027099-\$ or US-20030047795-\$ or US-20030141509-\$ or US-20030160253-\$ or US-20030173573-\$ or US-20030178631-\$ or US-20030209714-\$ or US-20030234400-\$ or US-20040144990-\$ or US-20040169180-\$ or US-20040183089-\$ or US-20030205711-\$).did. or (US-5042043-\$ or US-5326424-\$ or US-5612551-\$ or US-5929467-\$ or US-6064082-\$ or US-6069021-\$ or US-6078064-\$ or US-6121637-\$ or US-6150672-\$ or US-6194744-\$ or US-6266355-\$ or US-6316793-\$ or US-6339014-\$ or US-6342405-\$ or US-6372356-\$ or US-6392257-\$ or US-6541799-\$ or US-6613461-\$ or US-6730941-\$ or US-6787814-\$ or US-6797990-\$).did. or (JP-02288388-\$ or JP-05283744-\$ or JP-08064870-\$ or JP-08236810-\$ or JP-10032370-\$ or JP-10242514-\$ or JP-10242567-\$ or JP-10242569-\$ or JP-10247760-\$ or JP-11045892-\$ or JP-11199397-\$ or JP-11266006-\$ or JP-2000012896-\$ or JP-2000031164-\$ or JP-2000058451-\$ or JP-2000150957-\$ or JP-2000174342-\$ or JP-2000235956-\$ or JP-2001320089-\$ or JP-2002009340-\$).did. or (EP-395392-\$ or JP-05283744-\$ or JP-08064870-\$ or JP-08236810-\$ or JP-11045892-\$ or JP-11266006-\$ or JP-2000012896-\$ or JP-2000031164-\$ or US-6069021-\$ or JP-2000188260-\$ or JP-2000332294-\$ or JP-2000004046-\$ or US-20010054717-\$ or JP-2001320089-\$).did.	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2005/03/10 09:25
S33 8	24	S337 and (single adj crystal monocrystalline monocrystal) near6 (clad cladding nitride GaN)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 10:10

EAST Search History

S339	2	jp-2000188260\$-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 10:18
S340	35	"6069021"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 10:18
S341	2	("6069021").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 10:44
S342	8	(GaInN InGaN GaN InN "Ga.sub. "\$4"In.sub."\$4N "In.sub."\$4"Ga.sub. "\$4N) near10 (active light-emitting) adj2 (layer film) and (GaNP GaPN "GaN.sub."\$4"P.sub."\$4 "GaP.sub. "\$4"N.sub."\$4) near10 (clad cladding) adj2 (layer film)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/10 10:58
S343	5	(GaInN InGaN GaN InN "Ga.sub. "\$4"In.sub."\$4N "In.sub."\$4"Ga.sub. "\$4N) near10 (active light-emitting) adj2 (layer film) and (GaNP GaPN "GaN.sub."\$4"P.sub."\$4 "GaP.sub. "\$4"N.sub."\$4) near10 (clad cladding) adj2 (layer film) and (buffer intermediate matching) near5 (boron-based boron BP BN BPN BNP)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/10 10:59
S344	149	(single adj crystal monocrystalline) near4 mocvd	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/10 11:14
S345	67	(single adj crystal monocrystalline) near4 mocvd and nitride and buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/10 11:15
S346	54	(single adj crystal monocrystalline) near4 mocvd and nitride.ti,ab,clm. and buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/10 11:21
S347	35	(single adj crystal monocrystalline) near4 mocvd.ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/10 11:21

EAST Search History

S34 8	0	("udagawa.in.andmondt.xa").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/07 20:18
S34 9	1	udagawa.in. and mondt.xa.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/07 20:37
S35 0	4	((("6069021") or ("6339014")).PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/07 20:58
S35 1	11019	((257/79) or (257/8\$1) or (257/9\$1) or (257/100) or (257/101) or (257/102) or (257/103)).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/07 21:13
S35 2	0	S351 and (boron adj phoshphide BP) near4 buffer and (("Ga.sub."\$4 near10 "In.sub."\$4 "N") ("Ga.sub."\$4 "In.sub." "\$4"N")("In.sub."\$4 near10 "Ga.sub." "\$4 "N") ("In.sub."\$4 "Ga.sub."\$4"N")) near4 (light-emitting active) and (clad cladding) near4 (("Ga" near4 "N.sub." "\$4 near4 "P.sub."\$3) ("GaN.sub." "\$4"P.sub."\$3) ("Ga" near4 "P.sub."\$3 near4 "N.sub."\$3) ("GaP.sub."\$4"N. sub."\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/07 21:25
S35 3	19469	((257/79) or (257/8\$1) or (257/9\$1) or (257/100) or (257/101) or (257/102) or (257/103) or (372/4\$3)). CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/07 21:13
S35 4	0	S353 and (boron adj phoshphide BP) near4 buffer and (("Ga.sub."\$4 near10 "In.sub."\$4 "N") ("Ga.sub."\$4 "In.sub." "\$4"N")("In.sub."\$4 near10 "Ga.sub." "\$4 "N") ("In.sub."\$4 "Ga.sub."\$4"N")) near4 (light-emitting active) and (clad cladding) near4 (("Ga" near4 "N.sub." "\$4 near4 "P.sub."\$3) ("GaN.sub." "\$4"P.sub."\$3) ("Ga" near4 "P.sub."\$3 near4 "N.sub."\$3) ("GaP.sub."\$4"N. sub."\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/07 21:23

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S35 5	13802	((372/43\$4) or (372/44\$4) or (372/45\$4) or (372/46\$4) or (372/47\$4) or (372/48\$4) or (372/49\$4) or (372/50\$4)).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/07 21:24
S35 6	0	S355 and (boron adj phosphide BP) near4 buffer and (("Ga.sub."\$4 near10 "In.sub."\$4 "N") ("Ga.sub."\$4 "In.sub."\$4 "N") ("In.sub."\$4 near10 "Ga.sub."\$4 "N") ("In.sub."\$4 "Ga.sub."\$4 "N"))) near4 (light-emitting active) and (clad cladding) near4 (("Ga" near4 "N.sub."\$4 near4 "P.sub."\$3) ("GaN.sub."\$4 "P.sub."\$3) ("Ga" near4 "P.sub."\$3 near4 "N.sub."\$3) ("GaP.sub."\$4 "N.sub."\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/07 21:25
S35 7	6	"753393".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/15 22:56
S35 8	1	(US-20040144990-\$).did.	US-PGPUB	OR	OFF	2006/01/15 22:57
S35 9	2	("6069021").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/15 23:21
S36 0	2	("6339014").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/15 23:27
S36 1	1	("0000045").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/15 23:27
S36 2	4	S359 S360	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/15 23:27
S36 3	0	S362 and (single monocrystalline monocrystal) near10 (clad cladding)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/15 23:29

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S36 4	1	S362 and (single monocrystalline monocrystal) near20 (clad cladding)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/15 23:30
S36 5	0	ganp near10 (single-crystal monocrystalline single adj crystal) near10 (clad cladding)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/15 23:31
S36 6	0	(gallium adj alumin\$1um adj nitride adj phosphide ganp gapn) near10 (single-crystal monocrystalline single adj crystal) near10 (clad cladding)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/15 23:33
S36 7	0	(gallium adj alumin\$1um adj nitride adj phosphide ganp gapn "Ga" near1 "N.sub."\$3 near1 "P.sub."\$3) near10 (single-crystal monocrystalline single adj crystal) near10 (clad cladding)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/15 23:34
S36 8	2	S362 and mixed	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/15 23:35
S36 9	1	S358 and mixed	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/15 23:38
S37 0	306	single adj crystal near6 (clad cladding)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/15 23:38
S37 1	170	single adj crystal near6 (clad cladding).ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/15 23:38
S37 2	67	single adj crystal near3 (clad cladding).ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/15 23:39
S37 3	0	single adj crystal near3 (clad cladding).ti,ab,clm. and (clad cladding) near6 GaNP	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/15 23:39

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S37 4	0	single adj crystal near3 (clad cladding).ti,ab,clm. and (clad cladding) near6 GaN and phosphor\$3 near4 dop\$3 near6 (clad cladding)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/15 23:40
S37 5	1858	(single adj crystal monocrystal) near8 GaN gallium adj nitride near8 doped	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/16 08:24
S37 6	14	(single adj crystal monocrystal) near8 (GaN gallium adj nitride) near8 (n-doped phosphor\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/16 08:40
S37 7	5	(single adj crystal monocrystal) near8 (GaNP GaPN gallium adj nitride adj phosphide gallium adj phosphide adj nitride) and (clad cladding) adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/16 08:43
S37 8	9	(single adj crystal monocrystal) near8 (GaNP GaPN gallium adj nitride adj phosphide gallium adj phosphide adj nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/16 08:46
S37 9	259	(single adj crystal monocrystal) near8 ((clad cladding) adj layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/16 08:47
S38 0	36	(single adj crystal monocrystal) near2 ((clad cladding) adj layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/16 08:48
S38 1	36	(single adj crystal monocrystal) near2 ((clad cladding) adj layer) and (clad cladding) adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/16 09:29
S38 2	0	(single adj crystal monocrystal) near2 ((clad cladding) adj layer) near2 (GaN gallium adj nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/16 09:29
S38 3	7	(single adj crystal monocrystal) near4 ((clad cladding) adj layer) near4 (GaN gallium adj nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/16 09:30

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S38 4	7	(single adj crystal monocrystal) near4 ((clad cladding) adj layer) near4 (GaN gallium adj nitride) and (clad cladding) adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/16 09:31
S38 6	0	(single adj crystal monocrystal) near4 ((clad cladding) adj layer) near4 (GaN gallium adj nitride) and (clad cladding) adj layer and (recrystalliz\$5 crystalliz\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/16 09:33
S38 7	0	(lattice adj match\$3) near10 ("Ga" near1 "N.sub."\$3 near1 "P.sub."\$3 GaNP GaPN)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/16 09:53
S38 8	0	(lattice adj match\$3) near20 ("Ga" near1 "N.sub."\$3 near1 "P.sub."\$3 GaNP GaPN)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/16 09:59
S38 9	19	output near4 crystallinity and light-emitting adj diode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/16 10:01
S39 0	0	output near10 crystallinity near10 (cladding clad)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/16 10:03
S39 1	16	(efficiency output yield) near10 crystallinity near10 (cladding clad)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/16 15:33
S39 2	12509	((372/43.01) or (257/79) or (257/8\$1) or (257/9\$1) or (257/100) or (257/101) or (257/102) or (257/103)). CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/16 15:34
S39 3	0	S392 and ((Ga near1 "N.sub."\$3 near1 "P.sub."\$3) GaNP GaPN) near4 (clad cladding).ti,ab,clm. and lattice adj match\$3.ti,ab,clm. and buffer near4 (BPN BNP B near1 "N.sub."\$3 near1 "P.sub."\$3 BP-based BN-based).ti,ab,clm. and (single adj crystal monocrystal monocrystalline).ti,ab,clm. and (single adj heterojunction SH).ti,ab,clm. and (light adj emitting light-emitting).ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/16 15:39

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S39 4	0	S392 and ((Ga near1 "N.sub."\$3 near1 "P.sub."\$3) GaNP GaPN gallium adj nitride adj phosphide gallium adj phosphide adj nitride) near4 (clad cladding).ti,ab,clm. and lattice adj match\$3.ti,ab,clm. and buffer near4 (BPN BNP B near1 "N.sub."\$3 near1 "P.sub."\$3 BP-based BN-based).ti,ab,clm. and (single adj crystal monocrystal monocrystalline).ti,ab,clm. and (single adj heterojunction SH).ti,ab,clm. and (light adj emitting light-emitting).ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/16 15:39
S39 5	6	"753393".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/07/23 14:20
S39 6	0	S395 and monolayer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/07/23 14:20
S39 7	1	(US-20040144990-\$).did.	US-PGPUB	OR	OFF	2006/07/23 14:21
S39 8	0	S397 and monolayer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/07/23 14:22
S39 9	0	S397 and ((ALD) (monatomic single adj atomic) adj layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/07/23 14:22
S40 0	1	S397 and (buffer BP)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/07/23 15:33
S40 1	10	buffer adj layer near2 monolayer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/23 15:36
S40 2	6	"885943".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/23 16:02

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S40 3	2	("6069021").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/07/23 16:02
S40 4	1	S403 and (monolayer thick thcikness) and buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/23 16:08
S40 5	15131	((257/79) or (257/8\$1) or (257/9\$1) or (257/10\$1) or (372/43.01)).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/07/23 16:09
S40 6	26	S405 and GaN and buffer with (ALD monolayer single adj atomic)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/07/23 16:10
S40 7	28	S405 and GaN and buffer with (ALD monolayer single adj atomic)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/23 16:10
S40 8	28	S405 and GaN and buffer with (atomic adj layer adj deposition ALD monolayer single adj atomic)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/23 16:16
S40 9	29	S405 and GaN and buffer with (boron adj phosphide BP)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/23 16:16
S41 0	14802	((257/79) or (257/8\$1) or (257/9\$1) or (257/100) or (257/101) or (257/102) or (257/103) or (372/43.01) or (372/44.01)).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/01/03 15:21
S41 1	0	S410 and (ganp gapn) and (BP boron adj phosphide) near4 buffer and single adj heterojunction	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/01/03 15:23
S41 2	0	S410 and (ganp gapn ("Gan.sub."\$3 near2 "P.sub."\$3 near2 "N.sub."\$3)) and (BP boron adj phosphide) near4 buffer and single adj heterojunction	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/01/03 15:24

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S41 3	0	S410 and (ganp gapn ("Ga.sub."\$3 near2 "P.sub."\$3 near2 "N.sub."\$3)) and (BP boron adj phosphide) near4 buffer and single adj heterojunction	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/01/03 15:25
S41 4	1	S410 and (ganp gapn ("Ga.sub."\$3 near1 "P.sub."\$3 near1 "N.sub."\$3)) and (BP boron adj phosphide) near4 buffer and heterojunction	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/01/03 15:27
S41 5	2	("6787814").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/01/03 15:27
S41 6	2	jp-04297023\$-\$\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/01/03 17:08
S41 7	0	(boron adj phosphide BP) near4 buffer and (clad cladding) near4 (Ga near2 ("P.sub."\$3 near1 "N.sub."\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 17:10
S41 8	0	(boron adj phosphide BP) near4 buffer and (clad cladding) near8 (Ga near2 ("P.sub."\$3 near1 "N.sub."\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 17:11
S41 9	0	(boron adj phosphide BP BPN BNP boron near1 nitride) near4 buffer and (clad cladding) near8 (Ga near2 ("P.sub."\$3 near1 "N.sub."\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 17:13
S42 0	0	(boron adj phosphide BP BPN BNP boron near1 nitride) near8 buffer and (clad cladding) near8 (Ga near2 ("P.sub."\$3 near1 "N.sub."\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 17:13
S42 1	0	(boron adj phosphide BP BPN BNP boron near2 nitride) near8 buffer and (clad cladding) near8 (Ga near2 ("P.sub."\$3 near1 "N.sub."\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 17:30
S42 2	2	jp-02275682\$-\$\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 17:25

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S42 3	0	(boron adj phosphide BP BPN BNP boron near2 nitride gallium adj phosphide adj nitride gallium adj nitride adj phosphide) near8 buffer and (clad cladding) near8 (Ga near2 ("P.sub."\$3 near1 "N.sub."\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 17:38
S42 4	13	((("5,042,043") or ("6,372,356") or ("5,612,551") or ("6,121,637") or ("5,326,424") or ("6,069,021")).PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/01/03 18:09
S42 5	96	n-type near4 GaN same (P near4 dopant)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/01/03 18:10
S42 6	2	n-type near4 GaN same (P near4 dopant) and BP near3 buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/01/03 18:16
S42 7	96	n-type near4 GaN same (P near4 dopant)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/01/03 18:43
S42 8	2	"6069021".pn. and buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/01/03 18:43
S42 9	0	buffer same lattice-matching.clm. and light-emitting.ti,ab.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/01/04 12:01
S43 0	2	buffer same lattice adj matching.clm. and light-emitting.ti,ab.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/01/04 12:04
S43 1	15250	((257/79) or (257/8\$1) or (257/9\$1) or (257/100) or (257/101) or (257/102) or (257/103) or (257/190) or (372/43.01) or (372/44.01)).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/01/04 12:05
S43 2	3	S431 and (boron adj phosphide BP) near6 buffer and (GaN GaPN gallium adj nitride adj phosphide gallium adj phosphide adj nitride) and GaInN	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/04 12:36

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S43 3	3	udagawa.in. and (boron adj phosphide BP) near6 buffer and (GaNP GaPN gallium adj nitride adj phosphide gallium adj phosphide adj nitride) and GaInN	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 10:37
S43 4	3	(udagawa.in. (showa adj denko.as.)) and (boron adj phosphide BP) near6 buffer and (GaNP GaPN gallium adj nitride adj phosphide gallium adj phosphide adj nitride) and GaInN	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/04 12:41
S43 5	7	"332200".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/04 12:43
S43 6	5	"486985".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/04 12:44
S43 7	5	"502597".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/04 12:46
S43 8	6	"535821".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/04 12:48
S43 9	6	"536410".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/04 12:48